

2.5-V TO 3.3-V HIGH-PERFORMANCE CLOCK BUFFER

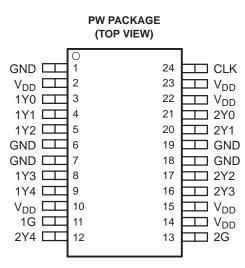
FEATURES

- High-Performance 1:10 Clock Driver
- Operates up to 200 MHz at V_{DD} 3.3 V
- Pin-to-Pin Skew < 100 ps at V_{DD} 3.3 V
- V_{DD} Range: 2.3 V to 3.6 V
- Operating Temperature Range –40°C to 85°C
- Output Enable Glitch Suppression
- Distributes One Clock Input to Two Banks of Five Outputs
- 25-Ω On-Chip Series Damping Resistors
- Packaged in 24-Pin TSSOP

APPLICATIONS

General-Purpose Applications

DESCRIPTION



The CDCVF2310 is a high-performance, low-skew clock buffer that operates up to 200 MHz. Two banks of five outputs each provide low-skew copies of CLK. After power up, the default state of the outputs is low regardless of the state of the control pins. For normal operation, the outputs of bank 1Y[0:4] or 2Y[0:4] can be placed in a low state when the control pins (1G or 2G, respectively) are held low and a negative clock edge is detected on the CLK input. The outputs of bank 1Y[0:4] or 2Y[0:4] can be switched into the buffer mode when the control pins (1G and 2G) are held high and a negative clock edge is detected on the CLK input. The device operates in a 2.5-V and 3.3-V environment. The built-in output enable glitch suppression ensures a synchronized output enable sequence to distribute full period clock signals.

The CDCVF2310 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

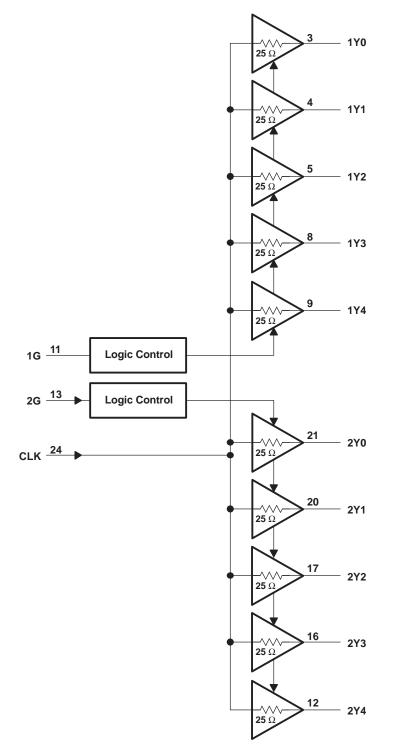
CDCVF2310

SCAS666C-JUNE 2001-REVISED JANUARY 2008



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



	INPUT			PUT
1G	2G	CLK	1Y[0:4]	2Y[0:4]
L	L	\downarrow	L	L
Н	L	\downarrow	CLK ⁽¹⁾	L
L	Н	Ļ	L	CLK ⁽¹⁾
Н	Н	\downarrow	CLK ⁽¹⁾	CLK ⁽¹⁾

FUNCTION TABLE

(1) After detecting one negative edge on the CLK input, the output follows the input CLK if the control pin is held high.

Terminal Functions

	TERMINAL	1/0	DESCRIPTION		
NAME	NO.	D. DESCRIPTION			
1G	11	I	Output enable control for 1Y[0:4] outputs. This output enable is active-high, meaning the 1Y[0:4] clock outputs follow the input clock (CLK) if this pin is logic high.		
2G	13	I	Output enable control for 2Y[0:4] outputs. This output enable is active-high, meaning the 2Y[0:4] clock outputs follow the input clock (CLK) if this pin is logic high.		
1Y[0:4]	3, 4, 5, 8, 9	0	Buffered output clocks		
2Y[0:4]	21, 20, 17, 16, 12	0	Buffered output clocks		
CLK	24	I	Input reference frequency		
GND	1, 6, 7, 18, 19		Ground		
V _{DD}	2, 10, 14, 15, 22, 23		DC power supply, 2.3 V – 3.6 V		

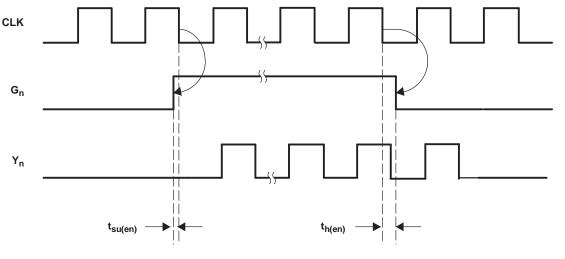


DETAILED DESCRIPTION

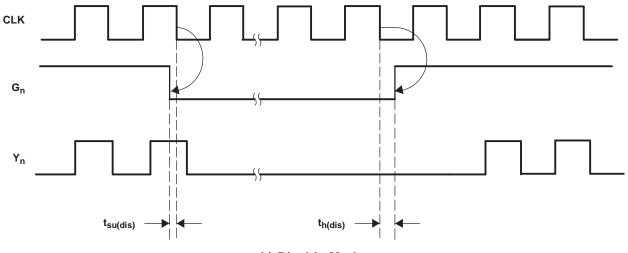
Output Enable Glitch Suppression Circuit

The purpose of the glitch suppression circuitry is to ensure the output enable sequence is synchronized with the clock input such that the output buffer is enabled or disabled on the next full period of the input clock (negative edge triggered by the input clock) (see Figure 1).

The G input must fulfill the timing requirements (t_{su}, t_h) according to the *Switching Characteristics* table for predictable operation.



a) Enable Mode



b) Disable Mode

Figure 1. Enable and Disable Mode Relative to $\text{CLK}{\downarrow}$

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

Supply voltage range, V _{DD}	–0.5 V to 4.6 V
Input voltage range, V _I ⁽²⁾⁽³⁾	-0.5 V to V _{DD} + 0.5 V
Output voltage range, V _O ⁽²⁾⁽³⁾	-0.5 V to V _{DD} + 0.5 V
Input clamp current, I_{IK} (V _I < 0 or V _I > V _{DD})	±50 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{DD})	±50 mA
Continuous total output current, $I_O (V_O = 0 \text{ to } V_{DD})$	±50 mA
Package thermal impedance, $\theta_{JA}^{(4)}$: PW package	120°C/W
Storage temperature range T _{stg}	–65°C to 150°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This value is limited to 4.6 V maximum.

(4) The package thermal impedance is calculated in accordance with JESD 51.

RECOMMENDED OPERATING CONDITIONS (1)

			MIN	NOM	MAX	UNIT	
			2.3	2.5		V	
Supply voltage, V _{DD}	voltage, V _{IL} $V_{DD} = 3 V \text{ to } 3.6 V$ Voltage, V _{IH} $V_{DD} = 2.3 V \text{ to } 2.7 V$ voltage, V _{IH} $V_{DD} = 3 V \text{ to } 3.6 V$ $V_{DD} = 2.3 V \text{ to } 2.7 V$ I $V_{DD} = 3 V \text{ to } 3.6 V$ $V_{DD} = 2.3 V \text{ to } 2.7 V$ $V_{DD} = 2.3 V \text{ to } 3.6 V$ $V_{DD} = 2.3 V \text{ to } 3.6 V$ $V_{DD} = 3 V \text{ to } 3.6 V$ $V_{DD} = 2.3 V \text{ to } 2.7 V$ $V_{DD} = 3 V \text{ to } 3.6 V$			3.3	3.6	v	
	$V_{DD} = 3 V \text{ to } 3.6 V$				0.8	V	
Low-level input voltage, V _{IL}	$V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}$				0.7	v	
	V _{DD} = 3 V to 3.6 V		2				
High-level input voltage, V _{IH}	V _{DD} = 2.3 V to 2.7 V		1.7			V	
Input voltage, V _I			0		V_{DD}	V	
Lich lovel output ourrest	$V_{DD} = 3 V \text{ to } 3.6 V$				12	~ ^	
High-level output current, I _{OH}	V _{DD} = 2.3 V to 2.7 V				6	mA	
	V _{DD} = 3 V to 3.6 V				12	~ ^	
Low-level output current, I _{OL}	V _{DD} = 2.3 V to 2.7 V		2.3 2.5 3.3 2 1.7	6	mA		
Operating free-air temperature, T,	el output current, I _{OL} $\frac{V_{DD} = 3 \text{ V to } 3.6 \text{ V}}{V_{DD} = 2.3 \text{ V to } 2.7 \text{ V}}$		-40		85	°C	

(1) Unused inputs must be held high or low to prevent them from floating.

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK}	Input voltage	V _{DD} = 3 V,	I _I = -18 mA			-1.2	V
I _I	Input current	$V_I = 0 V \text{ or } V_{DD}$				±5	μA
$I_{DD}^{(2)}$	Static device current	$CLK = 0 V \text{ or } V_{DD},$	$I_0 = 0 \text{ mA}$			80	μA
CI	Input capacitance	V_{DD} = 2.3 V to 3.6 V,	$V_I = 0 V \text{ or } V_{DD}$		2.5		pF
Co	Output capacitance	V_{DD} = 2.3 V to 3.6 V,	$V_I = 0 V \text{ or } V_{DD}$		2.8		pF

(1) All typical values are at respective nominal V_{DD}.

(2) For I_{CC} over frequency, see Figure 6.

$V_{DD} = 3.3 \text{ V} \pm 0.3 \text{ V}$

	PARAMETER	TEST COI	NDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
		V _{DD} = min to max,	I _{OH} = −100 μA	$V_{DD} - 0.2$			
V _{OH}	High-level output voltage	V - 2 V	I _{OH} = -12 mA	2.1			V
		$V_{DD} = 3 V$	I _{OH} = -6 mA	2.4			

(1) All typical values are at respective nominal V_{DD}.



$V_{DD} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (continued)

	PARAMETER	TEST	CONDITIONS	MIN TYP ⁽¹) MAX	UNIT
		V _{DD} = min to max,	I _{OL} = −100 μA		0.2	
V _{OL}	V _{OL} Low-level output voltage	N 2 M	I _{OL} = 12 mA		0.8	V
		$V_{DD} = 3 V$	$I_{OL} = 6 \text{ mA}$		0.55	
	V _{DD} = 3 V,	$V_0 = 1 V$	-28			
I _{OH}	High-level output current	V _{DD} = 3.3 V,	V _O = 1.65 V	-36	6	mA
		V _{DD} = 3.6 V,	V _O = 3.135 V		-14	
		$V_{DD} = 3 V,$	V _O = 1.95 V	28		
I _{OL}	Low-level output current	V _{DD} = 3.3 V,	V _O = 1.65 V	36	3	mA
		V _{DD} = 3.6 V,	$V_0 = 0.4 V$		14	

$V_{DD} = 2.5 V \pm 0.2 V$

	PARAMETER	TEST	CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V	High lovel output voltage	V_{DD} = min to max,	I _{OH} = −100 μA	V _{DD} - 0.2			V
V _{OH}	High-level output voltage	V _{DD} = 2.3 V	I _{OH} = -6 mA	1.8			v
V	Low-level output voltage	V _{DD} = min to max,	I _{OL} = 100 μA			0.2	V
V _{OL}	Low-level output voltage	V _{DD} = 2.3 V	$I_{OL} = 6 \text{ mA}$			0.55	v
		V _{DD} = 2.3 V,	$V_0 = 1 V$	-17			
I _{OH}	High-level output current	V _{DD} = 2.5 V,	V _O = 1.25 V		-25		mA
		V _{DD} = 2.7 V,	V _O = 2.375 V			-10	
		V _{DD} = 2.3 V,	V _O = 1.2 V	17			
I _{OL}	I _{OL} Low-level output current	V _{DD} = 2.5 V,	V _O = 1.25 V		25		mA
		V _{DD} = 2.7 V,	$V_{O} = 0.3 V$			10	

(1) All typical values are at respective nominal V_{DD} .

TIMING REQUIREMENTS

over recommended ranges of supply voltage and operating free-air temperature

			MIN	NOM	MAX	UNIT
£	Clock frequency	V _{DD} = 3 V to 3.6 V	0		200	MHz
Tclk	Clock frequency	V _{DD} = 2.3 V to 2.7 V	0		170	IVIF1Z

JITTER CHARACTERISTICS

Characterized using CDCVF2310 Performance EVM when V_{DD} =3.3 V. Outputs not under test are terminated to 50 Ω .

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
+		12 kHz to 5 MHz, $f_{out} = 30.72$ MHz	52		fo rmo	
ljitter	Additive phase jitter from input to output 1Y0	12 kHz to 20 MHz, f _{out} = 125 MHz		45		fs rms



SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

V_{DD} = 3.3 V ±0.3 V (see Figure 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH} t _{PHL}	CLK to Yn	f = 0 MHz to 200 MHz For circuit load, see Figure 2.	1.3		2.8	ns
t _{sk(o)}	Output skew (Ym to Yn) ⁽¹⁾ (see Figure 4)				100	ps
t _{sk(p)}	Pulse skew (see Figure 5)				250	ps
t _{sk(pp)}	Part-to-part skew				500	ps
t _r	Rise time (see Figure 3)	$V_{O} = 0.4 \text{ V} \text{ to } 2 \text{ V}$	0.7		2	V/ns
t _f	Fall time (see Figure 3)	$V_{O} = 2 V \text{ to } 0.4 V$	0.7		2	V/ns
t _{su(en)}	Enable setup time, G_high before CLK \downarrow		0.1			ns
t _{su(dis)}	Disable setup time, G_low before CLK \downarrow		0.1			ns
t _{h(en)}	Enable hold time, G_high after CLK \downarrow		0.4			ns
t _{h(dis)}	Disable hold time, G_low after CLK \downarrow		0.4			ns

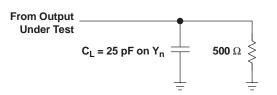
(1) The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.

V_{DD} = 2.5 V ±0.2 V (see Figure 2)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	CLK to Yn	f = 0 MHz to 170 MHz	1.5		3.5	ns
t _{PHL}		For circuit load, see Figure 2.				
t _{sk(o)}	Output skew (Ym to Yn) $^{(1)}$ (see Figure 4)				170	ps
t _{sk(p)}	Pulse skew (see Figure 5)				400	ps
t _{sk(pp)}	Part-to-part skew				600	ps
t _r	Rise time (see Figure 3)	$V_{O} = 0.4$ V to 1.7 V	0.5		1.4	V/ns
t _f	Fall time (see Figure 3)	V_{O} = 1.7 V to 0.4 V	0.5		1.4	V/ns
t _{su(en)}	Enable setup time, G_high before CLK \downarrow		0.1			ns
t _{su(dis)}	Disable setup time, G_low before CLK \downarrow		0.1			ns
t _{h(en)}	Enable hold time, G_high after CLK \downarrow		0.4			ns
t _{h(dis)}	Disable hold time, G_low after CLK \downarrow		0.4			ns

(1) The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.

PARAMETER MEASUREMENT INFORMATION



- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 200 MHz, Z₀ = 50 Ω , t_r < 1.2 ns, t_r < 1.2 ns.

Figure 2. Test Load Circuit

PARAMETER MEASUREMENT INFORMATION (continued)

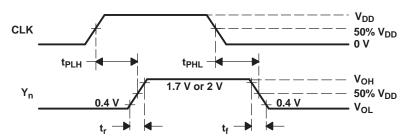


Figure 3. Voltage Waveforms Propagation Delay Times

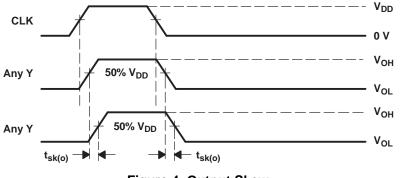
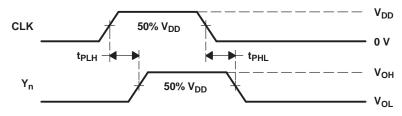


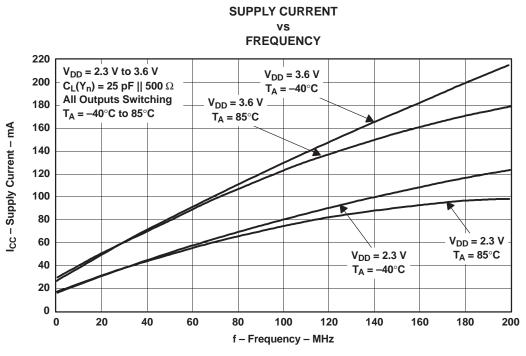
Figure 4. Output Skew



NOTE: $t_{sk(p)} = |t_{PLH} - t_{PHL}|$

Figure 5. Pulse Skew





PARAMETER MEASUREMENT INFORMATION (continued)



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CDCVF2310PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CDCVF2310PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CDCVF2310PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CDCVF2310PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

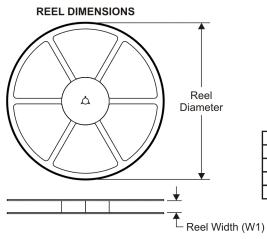
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

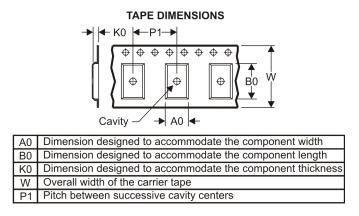
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



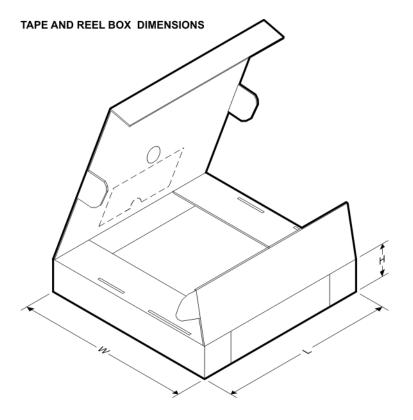
*All dimensions a	are nominal
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Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCVF2310PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCVF2310PWR	TSSOP	PW	24	2000	346.0	346.0	33.0

MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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